Thyristor Semiconductor Device - Page 1 of 1



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	re Material:
Metal	
Overall	-
0.210 in	
	Il Length:
0.500 in	
	Diameter:
0.230 in	
	Configuration:
Junction	
	ng Method:
Termina	
	Il Circle Diameter:
0.100 in	
	s Provided:
	cally sealed case
	nductor Material:
Silicon	
-	Rating In Volts Per Characteristic:
	eakover voltage, dc
	Rating Per Characteristic:
	peres source cutoff current
	Rating Per Characteristic:
	s small-signal input power, common-collector blank
	m Operating Tempurature Per Measurement Point:
	egrees celsius ambient air
	Features:
	pattern arrangement: pnpn
	Il Type And Quantity:
3 uninsu	lated wire lead
-	ation Data:
	elease4401 professional/industrial association specification
Shelf Li	ie:
N/a	
Unit Of	Measure:
Demilita	irization:
No	
Fiig:	
A110a0	